



INFORMATION DISCLOSURE STATEMENT BY APPLICANT		APPLICATION NO.: 09/935,776		ATTY. DOCKET NO.: H0498.70154US00	
		FILING DATE: August 22, 2001		CONFIRMATION NO.: 8935	
		APPLICANT: Lieber, et al.			
		GROUP ART UNIT: 2811		EXAMINER: Shouxiang Hu	
Sheet	1	of	2		

U.S. PATENT DOCUMENTS

Examiner's Initials	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication or of issue of Cited Document DD-MM-YYYY
		Number	Kind Code		
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OTHER ART – NON PATENT LITERATURE DOCUMENTS

Examiner's Initials	Cite No	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)	
SRL		Office Action mailed 01/03/2005 in U.S. Patent Application No. 10/196,337 filed July 16, 2002.		
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		GUO, Lingjie, et al., "Nanoscale Silicon Field Effect Transistors Fabricated Using Imprint Lithography," Appl. Phys. Lett. 71 (13), 29 September 1997, pages 1881 - 1883		
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Sheet	2	of	2	

<i>sk</i>		PADESTE, et al., "Modular Amperometric Immunosensor Devices", 1995, 8 th International Conference on Solid-State Sensors an Actuators and Eurosensors, June 25-29, 1995, pages 487-490.		
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EXAMINER: <i>Shouxiang Hu</i>		DATE CONSIDERED: <i>8/29/05</i>		

#EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

*a copy of this reference is not provided as it was previously cited by or submitted to the office in a prior application, Serial No. ___ filed ___, and relied upon for an earlier filing date under 35 U.S.C. 120 (continuation, continuation-in-part, and divisional applications).

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